

Conduction Cooled QCW Vertical Stack Diode Laser

GS05 Series



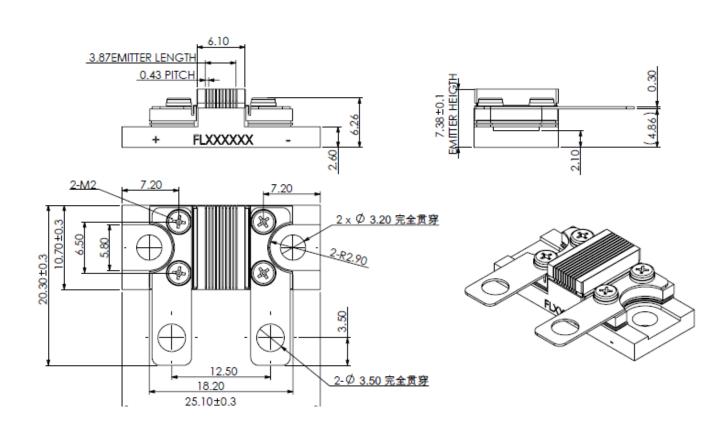
Features

- AuSn Bonding
- High reliability
- · Narrow spectrum
- · High peak power
- High temperature application
- · Compact Size

Applications

- Pumping
- Illumination
- Industry
- Research

Product Dimensions (mm)



Remark: The structure drawing is for reference only. Please feel free to contact us for any special requirements.



Product Specifications

Product Code	GST300166 ¹
Part No. ²	FL-GS05-10X1-2500-807(Q)

Part No. ²		FL-GS05-10X1-2500-807(Q)
General Data ³	Unit	
Operation Mode	-	QCW
Pulse Width	μs	200
Duty Cycle	%	1
Bar Pitch	mm	0.43
Optical Data ⁴		
Centroid Wavelength	nm	807
Wavelength Tolerance	nm	± 2
Output Power per Bar	W	250
Number of Bars	-	10
Spectral Width FWHM	nm	≤ 4
Spectral Width 90% Energy	nm	≤ 6
Fast Axis Divergence (FWHM)	0	35 (typical)
Slow Axis Divergence (FWHM)	0	8 (typical)
Polarization Mode	-	TE
Wavelength Temp. Coefficient	nm /°C	~ 0.28
Electrical Data 4		
Operation Current	А	≤ 260
Threshold Current	А	≤ 40
Operating Voltage per Bar	V	≤ 2
Slope Efficiency per Bar	W/A	≥1
Power Conversion Efficiency	%	≥ 50
Thermal Data		
Operating Temperature	°C	-45 ~ 60
Storage Temperature ⁵	°C	-55 ~ 85

¹Typical customization of products.

⁵ A non-condensing environment is required for storage and operation below ambient dew level.



²Part No. = Brand Code - Series - Power - Centroid Wavelength - Variant Code.

³ Reduced lifetime if used above nominal operating conditions.

⁴ Data at 25°C unless otherwise stated.